

EMIF01-5250SC5

Application Specific Discretes $A.S.D.^{TM}$

EMI FILTER WITH ESD PROTECTION

MAIN APPLICATIONS

Where EMI filtering in ESD sensitive equipment is required:

- Mobile phone : handsets and accessories
- RF communications

DESCRIPTION

The EMIF01-5250SC5 is a highly integrated T-filter designed to suppress EMI / RFI noise on I/O ports of mobile phones or RF communication equipment.

This filter includes ESD protection circuitry which prevents device destruction when subjected to ESD discharges.

The comprehensive layout of the EMIF01-5250SC5 filter allows design flexibility on high density boards.

FEATURES

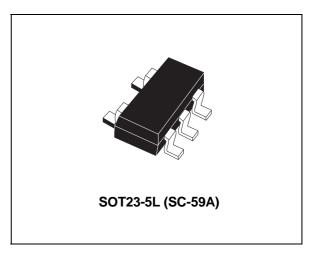
- T-filtering functions for 2 wires.
- ESD protection of 15 kV (air discharge) per IEC1000-4-2
- Breakdown voltage: V_{BR} = 6 V min.
- Low leakage current < 1 μA.

BENEFITS

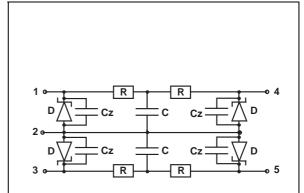
- EMI / RFI noise suppression.
- Enhanced ESD protection: IEC1000-4-2 level 4
- One of the smallest protection circuits available
- High flexibility in the design of high density boards

COMPLIES WITH THE FOLLOWING STANDARDS

IEC 1000-4-2 15kV (air discharge) 8 kV (contact discharge)



FUNCTIONAL DIAGRAM



 $R = 52 \Omega$ tolerance $\pm 15\%$

C = 50 pF tolerance $\pm 15\%$

D = Zener diode

Cz = Capacitance of the zener diode

October 1998 - Ed: 5A 1/5

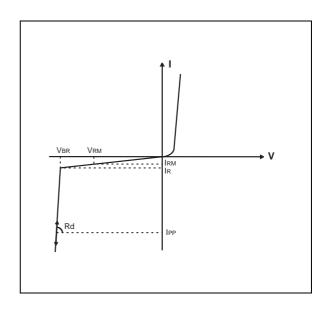
EMIF01-5250SC5

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \text{ }^{\circ}\text{C}$)

Symbol	Parameter and test conditions	Value	Unit
V _{PP}	ESD discharge IEC1000-4-2, air discharge	15	kV
	ESD discharge IEC1000-4-2, contact discharge	8	
Tj	Junction temperature	150	°C
Тор	Operating temperature range	-30 to + 85	°C
T _{stg}	Storage temperature range	-55 to +150	°C
TL	Lead temperature for soldering during 10s	260	°C

ELECTRICAL CHARACTERISTICS of the ZENER DIODE (Tamb = $25 \, ^{\circ}$ C)

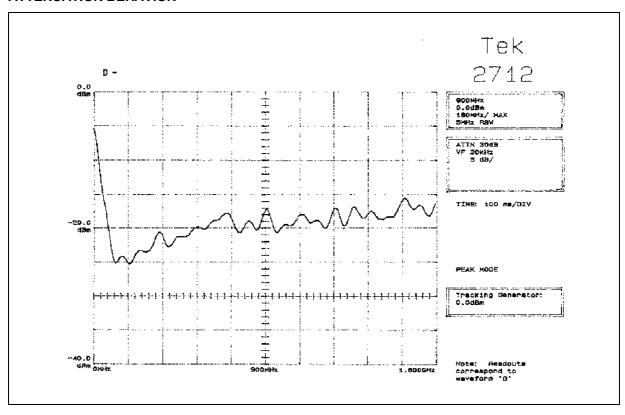
Symbol	Parameter
V _{BR}	Breakdown voltage
I _{RM}	Leakage current
Rd	Dynamic impedance
Cz	Zener capacitance
trr	Reverse recovery time

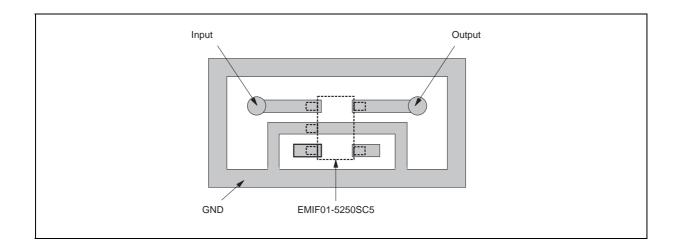


Symbol	Test conditions	Min.	Тур.	Max.	Unit
V _{BR}	$I_R = 1 \text{ mA}$	6	7	8	V
I _{RM}	$V_{RM} = 3V$			1	μΑ
Rd	$I_{pp} = 10 \text{ A}, t_p = 2.5 \mu\text{s}$		0.55		Ω
Cz	$0 \text{ V bias}, V_{RMS} = 30 \text{ mV}, F = 1 \text{ MHz}$		90		pF
trr	$I_F = 10$ mA, $dI_F/dt = 20$ A/ μ s, $R_L = 100$ Ω , $Tj = 25$ °C		40		ns

2/5

ATTENUATION BEHAVIOR





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ESD BEHAVIOR

Fig 2: ESD measurement conditions

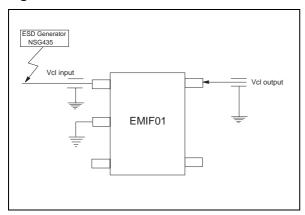
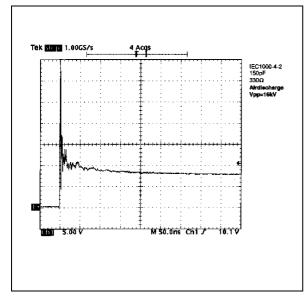
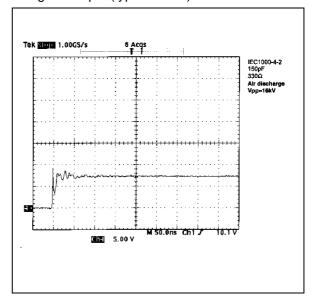


Fig 3: ESD behavior on IEC1000-4-2 air discharge at input (typical value)



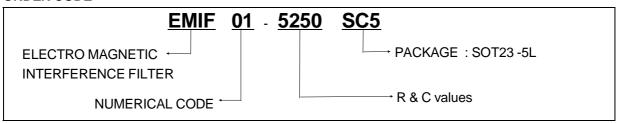
Figures 3 and 4 show the EMIF01-5250SC5 response to air and contact discharge conditions respectively at input and output pins. These figures indicate that the response is spontaneous and the output level is kept at safe operating voltages.

Fig 4: ESD behavior on IEC1000-4-2 air discharge at output (typical value)



4/5

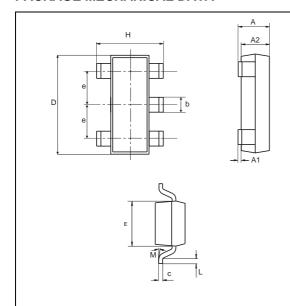
ORDER CODE



MARKING

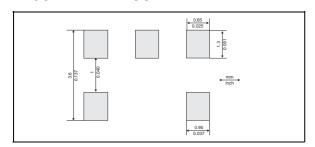
Type & order code	Marking	Packaging	Base qty (pcs)
EMIF01-5250SC5	EMIF	tape & reel	3000

PACKAGE MECHANICAL DATA



	DIMENSIONS					
REF.	Millimeters		Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.90		1.45	0.035		0.057
A1	0		0.15	0		0.006
A2	0.90		1.30	0.035		0.0512
b	0.35		0.50	0.0137		0.02
С	0.09		0.20	0.004		0.008
D	2.80		3.00	0.11		0.118
Е	1.50		1.75	0.059		0.0689
е		0.95			0.0374	
Н	2.60		3.00	0.102		0.118
L	0.10		0.60	0.004		0.024
М			10°			10°

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